

Advance Information

# Quad H-Bridge Micromotor Driver with DC/DC Boost Converter

The 17550 is a monolithic quad H-Bridge power IC ideal for portable electronic applications containing tiny bipolar stepper motors and/or brush DC-motors powered by two-to-four cell NiCd/NiMH batteries.

The 17550 operates from 2.5 V to 5.5 V, with independent control of each H-Bridge via parallel 3.0 V or 5.0 V logic-compatible I/O. The device features an on-board DC/DC boost converter that allows motor operation all the way down to 1.6 V (the boost converter supplies the gate-drive voltage for each of the four independent H-bridge output stages). Each output bridge has its own gate-drive and logic circuitry with built-in shoot-through current protection.

The 17550 has four operating modes: Forward, Reverse, Brake, and Tri-Stated (High Impedance). The 17550 has a low total  $R_{DS(ON)}$  of 1.2  $\Omega$  max @ 25°C. In addition, it can be set into a very low current-drain standby mode.

The H-Bridge outputs can be independently PWM'ed at up to 200 kHz for speed/torque and current control. The 17550 can efficiently drive many types of micromotors owing to its low output resistance and high output slew rates.

#### Features

- Low Total R<sub>DS(ON)</sub> 0.7 Ω (Typ), 1.2 Ω (Max) @ 25°C
- Output Current 700 mA (Continuous per Output)
- Shoot-Through Current Protection Circuit
- PWM Control Input Frequency up to 200 kHz
- Built-In DC/DC Boost Converter
- Low Power Consumption Standby Mode
- Undervoltage Detection and Shutdown Circuit
- Pb-Free Packaging Designated by Suffix Code EV

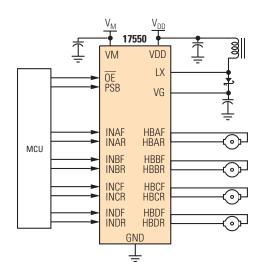


Figure 1. 17550 Simplified Application Diagram

 \* This document contains certain information on a new product. Specifications and information herein are subject to change without notice.
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**√RoHS** 

17550

#### H-BRIDGE MOTOR DRIVER



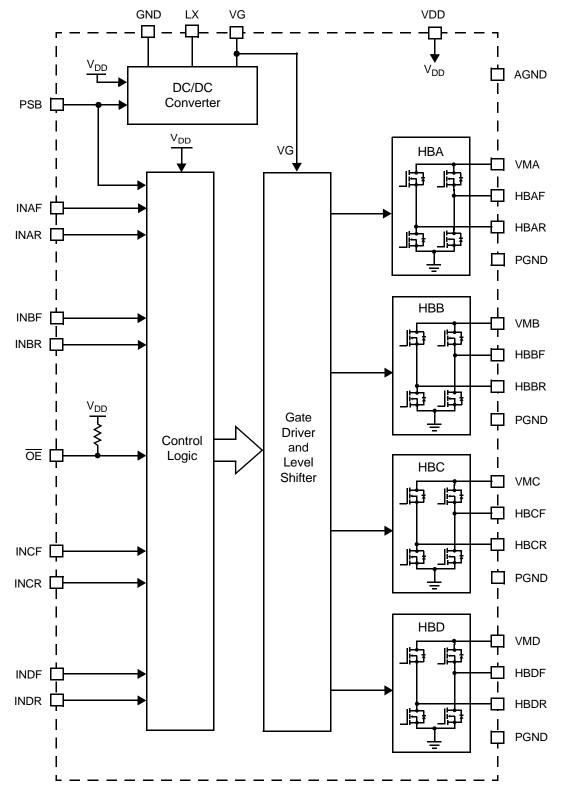
EV SUFFIX (Pb-FREE) 98ASA10591D 36-TERMINAL VMFP

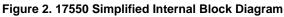
#### **ORDERING INFORMATION**

| Device        | Temperature<br>Range (T <sub>A</sub> ) Package |         |
|---------------|------------------------------------------------|---------|
| MPC17550EV/EL | -10°C to 60°C                                  | 36 VMFP |



## **INTERNAL BLOCK DIAGRAM**

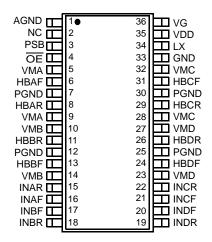


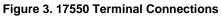


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## **TERMINAL CONNECTIONS**





#### Table 1. Terminal Function Description

| Terminal      | Terminal<br>Name | Formal Name                | Definition                                                  |
|---------------|------------------|----------------------------|-------------------------------------------------------------|
| 1             | AGND             | Analog Ground              | Analog and logic signal ground reference terminal.          |
| 2             | NC               | No Connect                 | No connection to this terminal.                             |
| 3             | PSB              | Power Standby              | Power standby mode control terminal.                        |
| 4             | OE               | Output Enable              | Logic output Enable control of H-Bridges (Low = True).      |
| 5,9           | VMA              | Motor Drive Power Supply A | Power supply voltage connection for Motor "A" (top of HBA). |
| 6             | HBAF             | HBA Forward Output         | Forward output of H-Bridge A.                               |
| 8             | HBAR             | HBA Reverse Output         | Reverse output of H-Bridge A.                               |
| 10, 14        | VMB              | Motor Drive Power Supply B | Power supply voltage connection for Motor "B" (top of HBB). |
| 11            | HBBR             | HBB Reverse Output         | Reverse output of H-Bridge B.                               |
| 7, 12, 25, 30 | PGND             | Power Ground               | Power ground connection.                                    |
| 13            | HBBF             | HBB Forward Output         | Forward output of H-Bridge B.                               |
| 15            | INAR             | Input Control HBA Reverse  | Control signal input for H-Bridge A reverse.                |
| 16            | INAF             | Input Control HBA Forward  | Control signal input for H-Bridge A forward.                |
| 17            | INBF             | Input Control HBB Forward  | Control signal input for H-Bridge B forward.                |
| 18            | INBR             | Input Control HBB Reverse  | Control signal input for H-Bridge B reverse.                |
| 19            | INDR             | Input Control HBD Reverse  | Control signal input for H-Bridge D reverse.                |
| 20            | INDF             | Input Control HBD Forward  | Control signal input for H-Bridge D forward.                |
| 21            | INCF             | Input Control HBC Forward  | Control signal input for H-Bridge C forward.                |
| 22            | INCR             | Input Control HBC Reverse  | Control signal input for H-Bridge C reverse.                |
| 23, 27        | VMD              | Motor Drive Power Supply D | Power supply voltage connection for Motor "D" (top of HBD). |
| 24            | HBDF             | HBD Forward Output         | Forward output of H-Bridge D.                               |
| 26            | HBDR             | HBD Reverse Output         | Reverse output of H-Bridge D.                               |
| 28, 32        | VMC              | Motor Drive Power Supply C | Power supply voltage connection for Motor "C" (top of HBC). |

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| Terminal | Terminal<br>Name | Formal Name                                                                                               | Definition                                                |
|----------|------------------|-----------------------------------------------------------------------------------------------------------|-----------------------------------------------------------|
| 29       | HBCR             | HBC Reverse Output                                                                                        | Reverse Output of H-Bridge C.                             |
| 31       | HBCF             | HCB Forward Output                                                                                        | Forward Output of H-Bridge C.                             |
| 33       | GND              | Ground                                                                                                    | Control circuit ground terminal for DC/DC circuit ground. |
| 34       | LX               | DC/DC Converter Switching Open-drain output of the internal DC/DC converter circuit.<br>Transistor Output |                                                           |
| 35       | VDD              | Logic Supply                                                                                              | Control circuit power supply terminal.                    |
| 36       | VG               | Gate-Driver Circuit Power<br>Supply                                                                       | Input terminal for the gate-drive voltage.                |

## Table 1. Terminal Function Description (continued)



# **ELECTRICAL CONNECTIONS**

#### **MAXIMUM RATINGS**

#### Table 2. Maximum Ratings

All voltages are with respect to ground unless otherwise noted. Exceeding the ratings may cause a malfunction or permanent damage to the device.

| Rating                                   | Symbol              | Value                        | Unit |  |
|------------------------------------------|---------------------|------------------------------|------|--|
| Motor Supply Voltage                     | V <sub>M</sub>      | -0.5 to 9.0                  | V    |  |
| Gate-Driver Circuit Power Supply Voltage | V <sub>G</sub>      | V <sub>DD</sub> -0.5 to 14   | V    |  |
| Logic Supply Voltage                     | V <sub>DD</sub>     | -0.5 to 6.0                  | V    |  |
| Signal Input Voltage <sup>(1)</sup>      | V <sub>IN</sub>     | -0.5 to V <sub>DD</sub> +0.5 | V    |  |
| Driver Output Current                    |                     |                              | А    |  |
| Continuous <sup>(2)</sup>                | ۱ <sub>0</sub>      | 0.7                          |      |  |
| Peak <sup>(3)</sup>                      | I <sub>OPK</sub>    | 2.0                          |      |  |
| ESD Voltage <sup>(4)</sup>               |                     |                              | V    |  |
| Human Body Model                         | V <sub>ESD1</sub>   | ±2000                        |      |  |
| Machine Model                            | V <sub>ESD2</sub>   | ±100                         |      |  |
| Storage Temperature Range                | T <sub>STG</sub>    | -65 to 150                   | °C   |  |
| Operating Ambient Temperature            | T <sub>A</sub>      | -10 to 60                    | °C   |  |
| Operating Junction Temperature           | Т <sub>Ј</sub>      | -10 to 150                   | °C   |  |
| Thermal Resistance <sup>(5)</sup>        | R <sub>0JA</sub>    | TBD                          | °C/W |  |
| Power Dissipation <sup>(6)</sup>         | PD                  | 1500                         | mW   |  |
| Soldering Temperature <sup>(7)</sup>     | T <sub>SOLDER</sub> | 260                          | °C   |  |

Notes

- 1.  $V_{IN}$  is the voltage level applied to any input terminal.
- 2.  $I_O$  is measured as the load current flowing through the H-bridge.
- 3.  $T_A = 25^{\circ}C$ , pulse width < 10 ms at intervals > 0.2 seconds.
- 4. ESD1 testing is performed in accordance with the Human Body Model (C<sub>ZAP</sub> = 100 pF, R<sub>ZAP</sub> = 1500 Ω), ESD2 testing is performed in accordance with the Machine Model (CZAP = 200 pF, RZAP = 0 Ω).
- 5. Mounted on 37 x 50 Cu area (1.6 mm FR-4 PCB).
- 6. Maximum at  $T_A = 25^{\circ}C$ .
- 7. Soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.



## STATIC ELECTRICAL CHARACTERISTICS

#### Table 3. STATIC ELECTRICAL CHARACTERISTICS

Characteristics noted under conditions  $T_A = 25^{\circ}C$ ,  $V_{DD} = 3.0$  V,  $V_M = 2.5$  V, GND = 0 V,  $f_{IN} = 176$  kHz unless otherwise noted. Typical values noted reflect the approximate parameter means at  $T_A = 25^{\circ}C$  under nominal conditions unless otherwise noted.

| Characteristic                                                                                                                                                                                 | Symbol                                                                            | Min                            | Тур                   | Max                               | Unit           |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|--------------------------------|-----------------------|-----------------------------------|----------------|
| POWER                                                                                                                                                                                          |                                                                                   | •                              |                       |                                   |                |
| Motor Supply Voltage                                                                                                                                                                           | V <sub>M</sub>                                                                    | 1.6                            | 2.5                   | 5.5                               | V              |
| Logic Supply Voltage                                                                                                                                                                           | V <sub>DD</sub>                                                                   | 2.5                            | 3.0                   | 5.5                               | V              |
| Standby Power Supply Current <sup>(8)</sup><br>Motor Supply Standby Current<br>Logic Supply Standby Current                                                                                    | I <sub>VMSTBY</sub><br>I <sub>VDDSTBY</sub>                                       |                                |                       | 1.0<br>1.0                        | μA             |
| Logic Supply Current                                                                                                                                                                           | I <sub>VDD</sub>                                                                  | -                              | 0.3                   | 1.0                               | mA             |
| Gate Driver Circuit Power Supply Current <sup>(9)</sup><br>Standby (PSB = "L")<br>No Signal Operating<br>Input Signal Operating <sup>(10)</sup><br>Driver Output ON Resistance <sup>(11)</sup> | I <sub>DDC0</sub><br>I <sub>DDCN</sub><br>I <sub>DDC</sub><br>R <sub>DS(ON)</sub> | -<br>-<br>-                    | -<br>1.0<br>19<br>0.7 | 1.0<br>3.0<br>25<br>1.2           | μA<br>μA<br>mA |
| GATE DRIVE Gate Driver Circuit Power Supply Voltage <sup>(12)</sup>                                                                                                                            | V <sub>G</sub>                                                                    | 10                             | 11.5                  | 13                                | V              |
| CONTROL LOGIC                                                                                                                                                                                  | 0                                                                                 |                                |                       |                                   | l              |
| Logic Input Voltage <sup>(13)</sup>                                                                                                                                                            | V <sub>IN</sub>                                                                   | 0                              | _                     | V <sub>DD</sub>                   | V              |
| Logic Input (F, R, PSB, OE)                                                                                                                                                                    |                                                                                   |                                |                       |                                   |                |
| High-Level Input Voltage<br>Low-Level Input Voltage<br>High-Level Input Current                                                                                                                | V <sub>IH</sub><br>VIL<br>I <sub>IH</sub>                                         | V <sub>DD</sub> x0.7<br>-<br>- | -<br>-<br>-           | -<br>V <sub>DD</sub> x 0.3<br>1.0 | ν<br>ν<br>μΑ   |
| Low-Level Input Current                                                                                                                                                                        | ۱ <sub>IL</sub>                                                                   | -1.0                           | -                     | -                                 | μΑ             |

Notes

8. Applies individually to each H-Bridge.

9. Average inductor current for DC/DC converter (connected between V<sub>DD</sub> and LX [L = 1.0 mH, C = 2.2  $\mu$ F]).

10. Full drive (input signal to all input control terminals).

11. The total H-bridge ON resistance when  $V_{G} \mbox{ is } 11.5 \mbox{ V}.$ 

12. When voltage is supplied externally without built-in DC/DC.

13. V<sub>IN</sub> is the voltage level applied to any input.



## DYNAMIC ELECTRICAL CHARACTERISTICS

#### Table 4. DYNAMIC ELECTRICAL CHARACTERISTICS

Characteristics noted under conditions  $T_A = 25^{\circ}C$ ,  $V_{DD} = 3.0$  V,  $V_M = 2.5$  V, GND = 0 V,  $f_{IN} = 176$  kHz unless otherwise noted. Typical values noted reflect the approximate parameter means at  $T_A = 25^{\circ}C$  under nominal conditions unless otherwise noted.

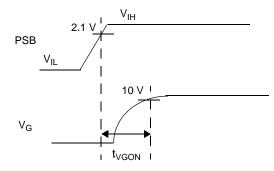
| Characteristic                                | Symbol            | Min | Тур | Max | Unit |
|-----------------------------------------------|-------------------|-----|-----|-----|------|
| INPUT                                         |                   | •   |     | L   |      |
| Pulse Input Frequency <sup>(14)</sup>         | f <sub>IN</sub>   | -   | -   | 200 | kHz  |
| Internal Oscillator Frequency                 | f <sub>osc</sub>  | -   | 100 | 200 | kHz  |
| OUTPUT                                        | ·                 |     |     |     |      |
| Gate Driver Circuit Power Supply Wake-Up Time | t <sub>VGON</sub> | -   | 10  | 20  | ms   |
| Propagation Delay Time                        |                   |     |     |     | μs   |
| Turn-ON Time                                  | t <sub>PLH</sub>  | -   | 0.2 | 1.0 |      |
| Turn-OFF Time                                 | t <sub>PHL</sub>  | -   | 0.2 | 1.0 |      |

Notes

14.  $f_{IN}$  is the signal frequency applied to an input terminal (F, R).



## **TIMING DIAGRAMS**



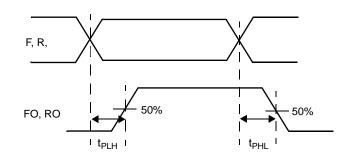


Figure 5. H-Bridge Output Waveform

Figure 4. DC/DC Converter Output Waveform



| PSB, OE |    | INA/INB/INC/IND |      | HBA/HBB/HBC/HBC |   |
|---------|----|-----------------|------|-----------------|---|
| PSB     | OE | IN*F            | IN*R | HB*F HB*R       |   |
| Н       | L  | L               | L    | L               | L |
| Н       | L  | L               | Н    | L               | Н |
| Н       | L  | Н               | L    | Н               | L |
| Н       | L  | Н               | Н    | Z               | Z |
| Н       | Н  | Х               | Х    | Z               | Z |
| L       | X  | Х               | Х    | Z               | Z |

H = High.L = Low.

Z = High impedance.

X = Don't care.

\* = A, B, C, or D.



# FUNCTIONAL DESCRIPTION

#### **INTRODUCTION**

The 17550 is a monolithic quad H-Bridge ideal for portable electronic applications containing multiple bipolar stepper motors and/or brush DC motors. The device features an onboard DC/DC converter to provide gate-drive voltages, as well as level-shifting circuitry. The control logic translates the input signals to the gate-driver circuitry while providing cross-conduction suppression. The 17550 has four operating modes: Forward, Reverse, Brake, and Tri-Stated (High Impedance). The MOSFETs comprising the output bridge have a total source+sink  $R_{DS(ON)} \leq 1.2~\Omega.$ 

The 17550 can simultaneously drive four brush DC motors or two bipolar stepper motors. The drivers are designed to be PWM'ed at frequencies up to 200 kHz.

## FUNCTIONAL TERMINAL DESCRIPTION

### LOGIC SUPPLY (VDD)

The VDD terminal carries the logic supply voltage and current into the logic sections of the IC. V<sub>DD</sub> has an undervoltage threshold. If the supply voltage drops below the undervoltage threshold, the output power stage switches to a tri-state condition. When the supply voltage returns to a level that is above the threshold, the power stage automatically resumes normal operation according to the established condition of the input control terminals.

### CONTROL SIGNAL INPUT FOR H-BRIDGE, F=FORWARD, R= REVERSE (INAF, INAR, INBF, INBR, INCF, INCR, INDF, INDR)

These logic input control terminals control each H-Bridge output; e.g., IN\*F logic HIGH = HB\*F HIGH; likewise, IN\*R logic HIGH = HB\*R HIGH. However, if both "F" and "R" inputs are taken HIGH, the associated bridge's outputs are both tristated (refer to Table <u>5, Truth Table</u>, page <u>8</u>).

## OUTPUT ENABLE (OE)

 $\overline{OE}$  terminal is a LOW = TRUE enable input. When  $\overline{OE}$  = HIGH, all H-Bridge outputs are tri-stated (high impedance) regardless of logic inputs states.

#### OUTPUT OF H-BRIDGE, R=REVERSE, F=FORWARD (HBAF, HBAR, HBBF, HBBR, HBCF, HBCR, HBDF, HBDR)

These terminals provide connection to the outputs of each of the internal H-Bridges (see Figure 2, 17550 Simplified Internal Block Diagram, page 2).

POWER SUPPLY VOLTAGE CONNECTION FOR MOTORS A, B, C, D (VMA, VMB, VMC, VMD)

The VM terminals carry the main supply voltage and current into the power sections of the 17550. This supply then becomes controlled and/or modulated by the 17550 as it delivers the power to the loads attached between the H-Bridge output terminals. All VM terminals must be connected together on the printed circuit board.

# DC/ DC CONVERTER SWITCHING TRANSISTOR OUTPUT (LX)

The LX terminal is the open-drain output of the internal DC/DC converter circuit. It is the junction for the external inductor and the anode of the external Schottky diode.

### GATE-DRIVER CIRCUIT POWER SUPPLY (VG)

The VG terminal is the input terminal for the gate-drive voltage. It can be supplied from the built-in DC/DC converter or from an external source.

### **GROUND TERMINALS (GND, AGND, PGND)**

All ground terminals must be tied together on the PCB.

### **POWER STANDBY MODE CONTROL (PSB)**

The PSB input controls the functioning of power output stages (the H-Bridges). When this input signal turns Low, the output stages and Internal DC/DC Converter which makes Gate Voltage are disabled and all the outputs are opened (High Impedance). When this input signal turns High, the output stages and Internal DC/DC Converter are enabled and the H-Bridges operate normally.



# **TYPICAL APPLICATIONS**

#### **INTRODUCTION**

The 17550's built-in DC/DC converter must be connected to an external inductor, rectifier, and filter capacitor. This step-up converter generates the gate-drive voltage,  $V_G$ , required by the internal gate driver circuits. Although there is some latitude in selecting the values for the external component, care must be taken that  $V_G$  does not exceed 14 V. Additionally, too low an inductance will cause large instantaneous switching currents, which may damage the device.

**Important** Do not use an inductance lower than 330  $\mu$ H. To attain high-efficiency operation, the rectifier should be a Schottky diode, and the filter capacitor should be of the low

Equivalent Series Resistance (ESR) type. Attention should be paid to proper switch mode power supply PCB layout practice. Some experimentation may be required to determine optimal external component values. The recommended starting values are L = 1.0 mH, C = 2.2  $\mu$ F.

The DC/DC converter includes its own internal oscillator and does not require an external clock input.

#### **TYPICAL APPLICATION**

Two typical application schematics are shown in <u>Figure 6</u>. and <u>Figure 7</u>.

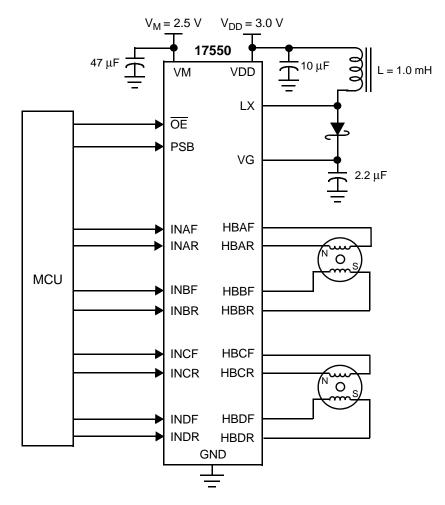


Figure 6. Typical 17550 Application - Controlling Stepper Motors



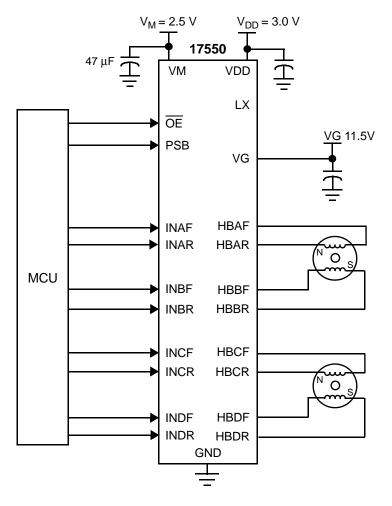


Figure 7. Typical 17550 Application - No Internal DC-DC Used



#### **CEMF SNUBBING TECHNIQUES**

Care must be taken to protect the IC from potentially damaging CEMF spikes induced when commuting currents in inductive loads. Typical practice is to provide snubbing of voltage transients by placing a capacitor or zener at the motor supply voltage terminal (VM) (see Figure 8).

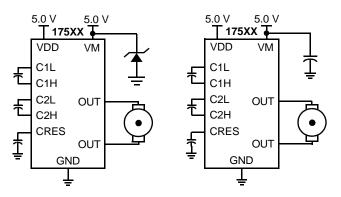


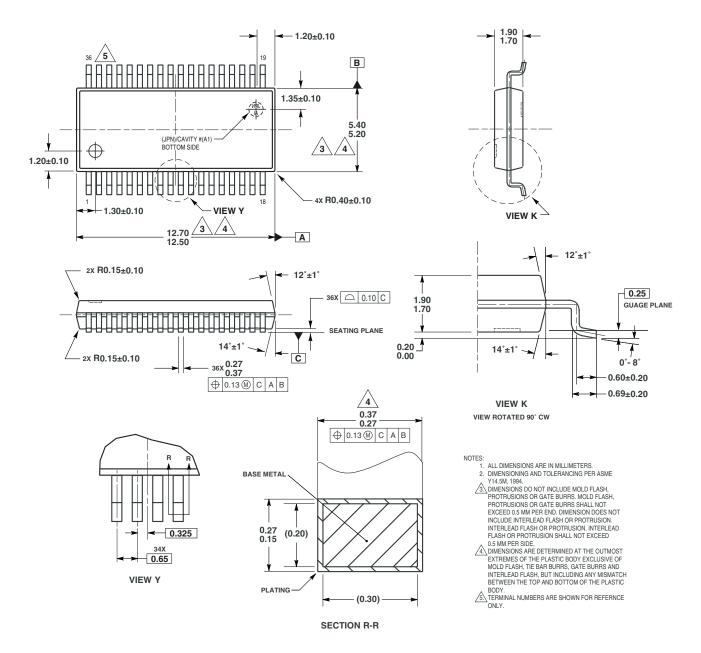
Figure 8. CEMF Snubbing Techniques



# PACKAGING

## **PACKAGE DIMENSIONS**

**Important:** For the most current revision of the package, visit <u>www.freescale.com</u> and perform a keyword search on the 98A number listed below.



EV (Pb-FREE) SUFFIX 36-LEAD VMFP PLASTIC PACKAGE CASE 1522-01 ISSUE O



# **REVISION HISTORY**

| REVISION | DATE   | DESCRIPTION OF CHANGES                                                                                                                                                             |
|----------|--------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 2.0      | 7/2006 | <ul> <li>Converted to Freescale format and updated to the prevailing form and style</li> <li>Added typical Application for non DC/DC use</li> <li>Added RoHS compliance</li> </ul> |



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